NSN 5962-01-051-3013



Memory Microcircuit - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5962-01-051-3013 **Body Length:** Between 1.190 inches and 1.230 inches **Body Width:** Between 0.580 inches and 0.610 inches **Body Height:** Between 0.080 inches and 0.120 inches **Maximum Power Dissipation Rating:** 675.0 milliwatts **Operating Tempurature Range:** +0.0/+75.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and monolithic and positive outputs and schottky and high speed and w/enable and w/storage and w/strobe and w/disable and 3-state output and programmable and programmed and w/decoded output **Inclosure Material:** Ceramic and metal **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 12 input **Voltage Rating And Type Per Characteristic:** 5.5 volts power source **Time Rating Per Chacteristic:** 35.00 nanoseconds propagation delay time, low to high level output and 45.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Prom **Memory Capacity: Precious Material And Location:** Terminals gold

Terminal Type And Quantity:

24 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

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